

HD14572UB

Hex Gate

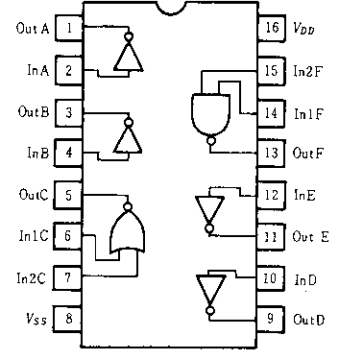
(4-Inverter
2-input NOR Gate
2-input NAND Gate)

The HD14572UB hex functional gate finds primary use where low power dissipation and/or high noise immunity is desired. The chip contains four inverters, one NOR gate and one NAND gate.

FEATURES

- Quiescent Current $\approx 0.5\text{nA/pkg typ. @5V}$
- Supply Voltage Range = 3 to 18V
- NOR Input Pin Adjacent to V_{SS} Pin to Simplify Use As An Inverter
- NAND Input Pin Adjacent to V_{DD} Pin to Simplify Use As An Inverter
- NOR Output Pin Adjacent to Inverter Input Pin For OR Application
- NAND Output Pin Adjacent to Inverter Input Pin For AND Application
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range

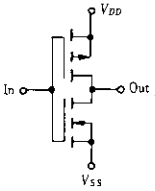
PIN ARRANGEMENT



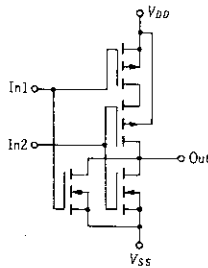
(Top View)

CIRCUIT SCHEMATIC

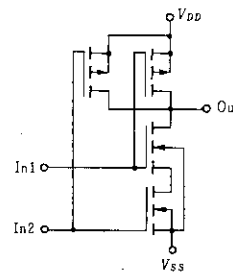
Inverter



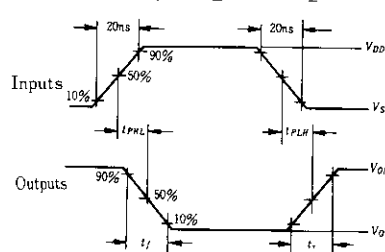
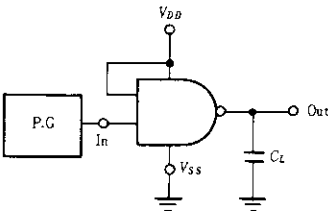
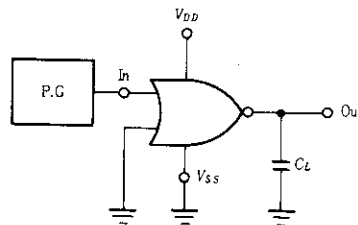
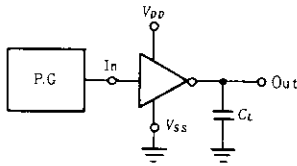
NOR



NAND



SWITCHING TIME TEST CIRCUIT



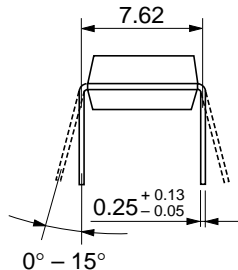
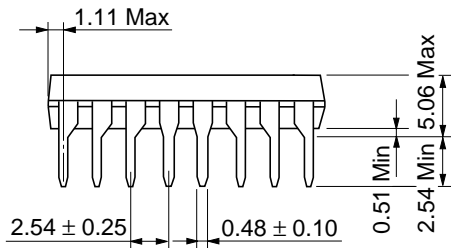
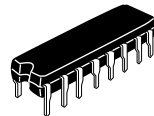
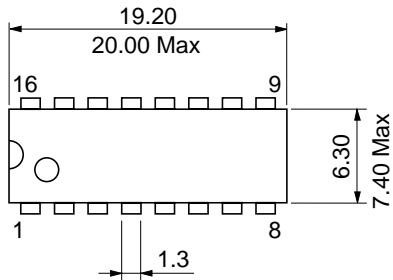
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	V _{DD} (V)	Test Conditions	-40°C		25°C			85°C		Unit
				min	max	min	typ	max	min	max	
Output Voltage	V _{OL}	5.0	V _{in} = V _{DD}	—	0.05	—	0	0.05	—	0.05	V
		10		—	0.05	—	0	0.05	—	0.05	
		15		—	0.05	—	0	0.05	—	0.05	
	V _{OH}	5.0	V _{in} = 0	4.95	—	4.95	5.0	—	4.95	—	V
		10		9.95	—	9.95	10	—	9.95	—	
		15		14.95	—	14.95	15	—	14.95	—	
Input Voltage	V _{IL}	5.0	V _{ovt} = 4.5V	—	1.0	—	2.25	1.0	—	1.0	V
		10	V _{ovt} = 9.0V	—	2.0	—	4.50	2.0	—	2.0	
		15	V _{ovt} = 13.5V	—	2.5	—	6.75	2.5	—	2.5	
	V _{IH}	5.0	V _{ovt} = 0.5V	4.0	—	4.0	2.75	—	4.0	—	V
		10	V _{ovt} = 1.0V	8.0	—	8.0	5.50	—	8.0	—	
		15	V _{ovt} = 1.5V	12.5	—	12.5	8.25	—	12.5	—	
Output Drive Current	I _{OH}	5.0	V _{OH} = 2.5V	-1.0	—	-0.8	-1.7	—	-0.6	—	mA
		5.0	V _{OH} = 4.6V	-0.2	—	-0.16	-0.36	—	-0.12	—	
		10	V _{OH} = 9.5V	-0.5	—	-0.4	-0.9	—	-0.3	—	
	15	V _{OH} = 13.5V	-1.4	—	-1.2	-3.5	—	-1.0	—		
	I _{OL}	5.0	V _{OL} = 0.4V	0.52	—	0.44	0.88	—	0.36	—	mA
		10	V _{OL} = 0.5V	1.3	—	1.1	2.25	—	0.9	—	
15		V _{OL} = 1.5V	3.6	—	3.0	8.8	—	2.4	—		
Input Current	I _{in}	15		—	±0.3	—	+0.0001	±0.3	—	±1.0	μA
Input Capacitance	C _{in}		V _{in} = 0	—	—	—	5.0	7.5	—	—	pF
Quiescent Current	I _{DD}	5.0	Zero Signal, per Package	—	0.5	—	0.0005	0.5	—	3.8	μA
		10		—	1.0	—	0.0010	1.0	—	7.5	
		15		—	2.0	—	0.0015	2.0	—	15	
Total Supply Current*	I _T	5.0	Dynamic + I _{DD} , per Gate,	—	—	—	1.89	—	—	—	μA
		10		—	—	—	3.80	—	—	—	
		15		—	—	—	5.68	—	—	—	

* To calculate total supply current at frequency other than 1kHz.
 @ V_{DD} = 5.0V I_T = (1.89 μA/kHz)f + I_{DD}. @ V_{DD} = 10V I_T = (3.80 μA/kHz)f + I_{DD}. @ V_{DD} = 15V I_T = (5.68 μA/kHz)f + I_{DD}.

SWITCHING CHARACTERISTICS (C_L = 50pF, T_a = 25°C)

Characteristic	Symbol	V _{DD} (V)	min	typ	max	Unit
Output Rise Time	t _r	5.0	—	180	400	ns
		10	—	90	200	
		15	—	65	160	
Output Fall Time	t _f	5.0	—	100	200	ns
		10	—	50	100	
		15	—	37	80	
Propagation Delay Time	t _{PLH}	5.0	—	115	200	ns
		10	—	55	110	
		15	—	40	85	
	t _{FHL}	5.0	—	115	200	ns
		10	—	55	110	
		15	—	40	85	



Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe GmbH
Electronic components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 049318
Tel: 535-2100
Fax: 535-1533

Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building, No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281
Telex: 40815 HITEC HX

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